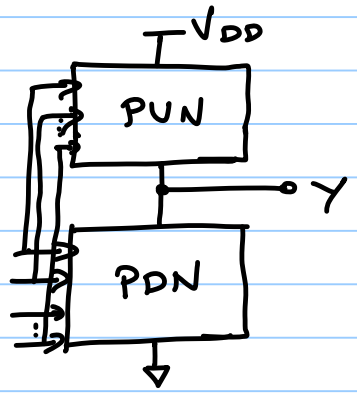
20/09/2019

EE5311

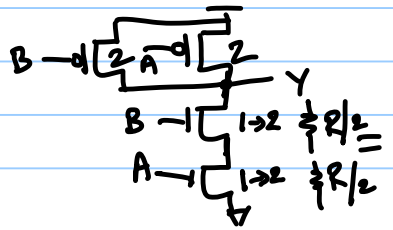
MODULE 4- COMBINATIONAL CIRCUITS

$Y = f(A, B, C \ldots)$
$= \sum m(0, 1, 2 \ldots)$

① $\bar{Y} = f(A, B, C \ldots)$

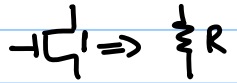


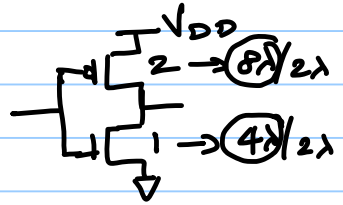
NAND2:



$Y = \overline{AB}$

R

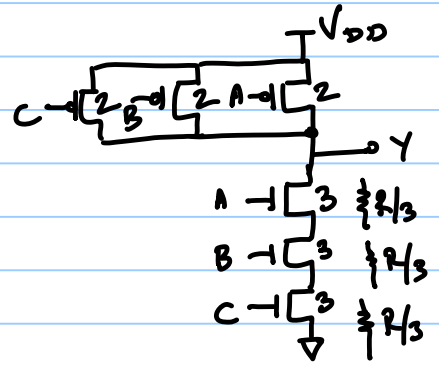




NAND3:

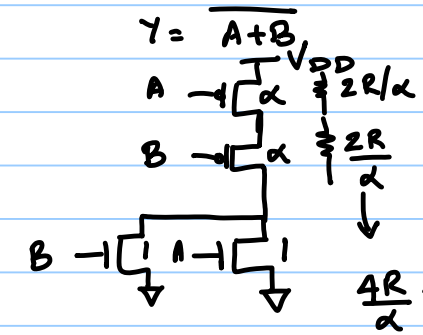
$Y = \overline{ABC}$

$\overline{Y} = ABC$



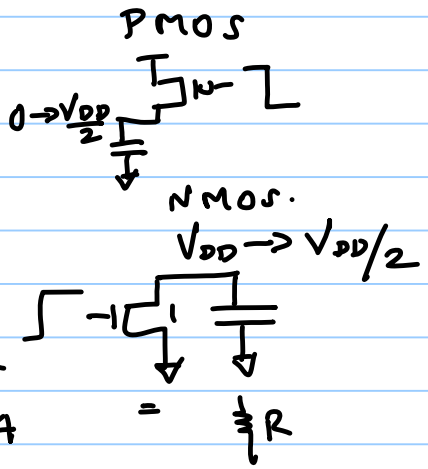
NOR2

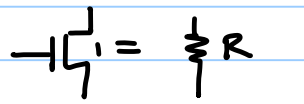
$Y = \overline{A+B}$



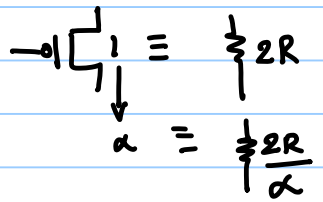
$\frac{4R}{\alpha} = R$

$\Rightarrow \alpha = 4$



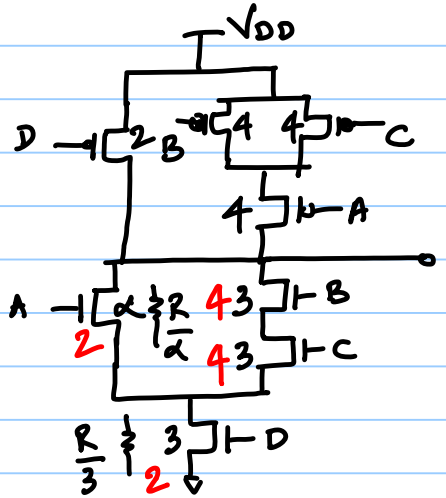


$R_N = \frac{3V_{DD}}{4 I_{DSAT-N}}$



$R_p = \frac{3V_{DD}}{4 I_{DSAT-P}}$

$$Y = \overline{(A + BC)D}$$



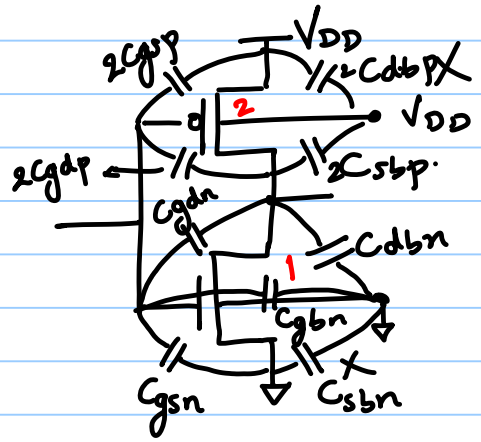
$$\frac{R}{\alpha} + \frac{R}{3} = R$$

$$\therefore (\alpha = 3/2)$$

$$\Sigma W_i^0 = 12$$

$$\Sigma W_i^0 = 10.5$$

CAPACITANCE



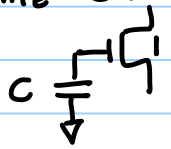
ALL CAPS SCALE AS $\propto W$

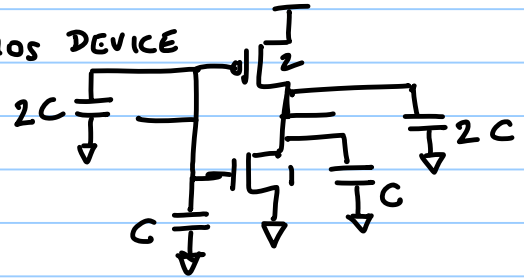
$C_{gsn} = C_{gsp}$

ASSUMPTIONS:

1) LUMP ALL CAPS.
2) ALL CAPS TO AC GND
3) ALL CAPS ARE EQUAL

C → GATE CAP OF A UNIT NMOS DEVICE





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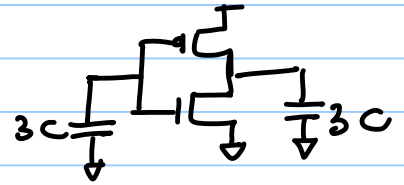
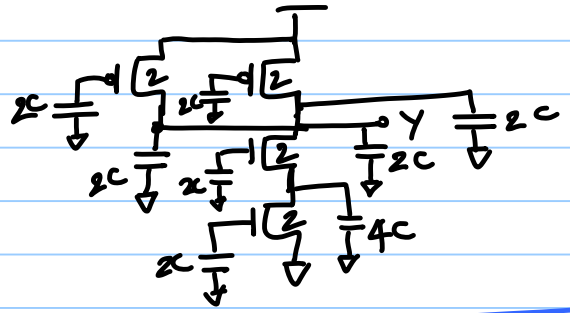
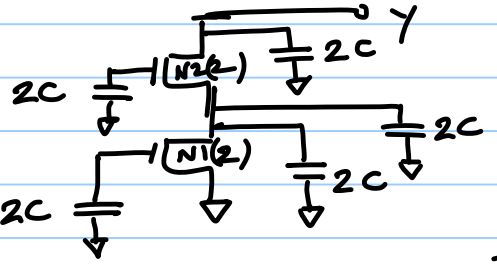
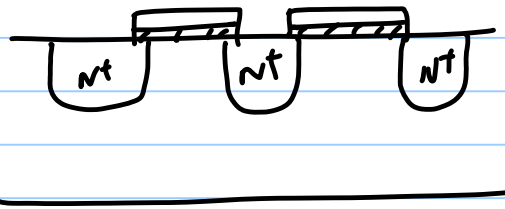


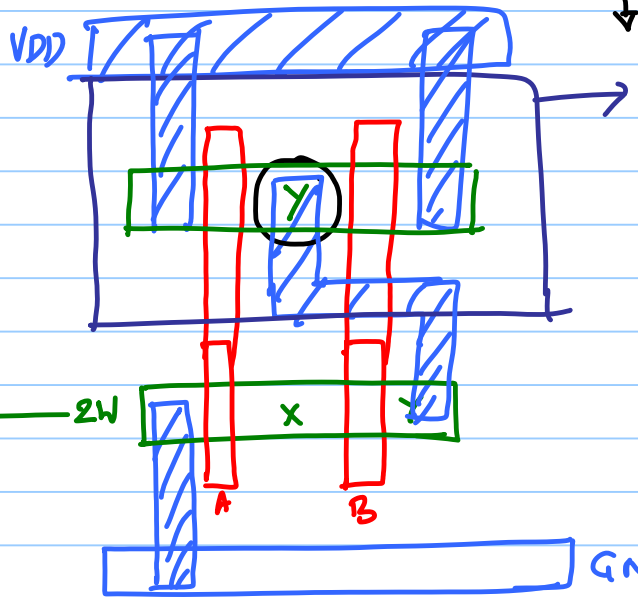


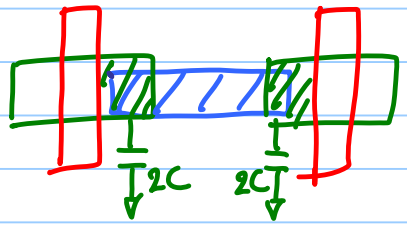


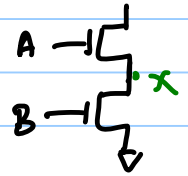
UNCONTACTED SHARED DIFFUSION

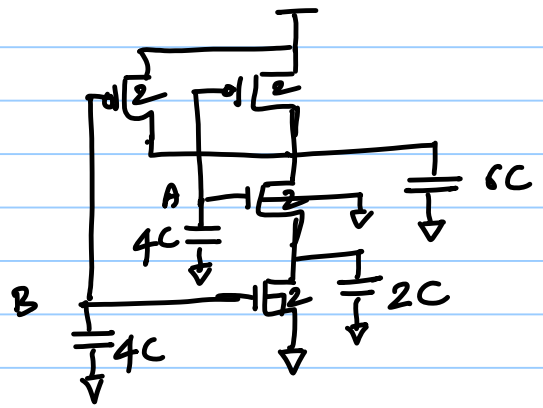
⇒ DO NOT DOUBLE COUNT CAP










A
B
4C
6C
2C
4C